

	Type	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition
1	BRS	3590	epitax\$3 and (silicon or Si) and (antimony or Sb)	USPAT; US-PGPUB; 2002/06/20 DERWENT; IBM_TDB 11:22			
2	BRS	120	(epitax\$3 and (silicon or Si) and (antimony or Sb)) and (heavily-doped)	USPAT; US-PGPUB; 2002/06/20 DERWENT; IBM_TDB 11:05			
3	BRS	5	(epitax\$3 and (silicon or Si) and (antimony or Sb)) and (heavily-doped with (indium or In))	USPAT; US-PGPUB; 2002/06/20 DERWENT; IBM_TDB 11:01			
4	BRS	844	epitax\$3 and (silicon or Si) and (antimony or Sb) and (indium or In)	USPAT; US-PGPUB; 2002/06/20 DERWENT; IBM_TDB 11:05			
5	BRS	24	(epitax\$3 and (silicon or Si) and (antimony or Sb) and (indium or In)) and (heavily-doped)	USPAT; US-PGPUB; 2002/06/20 DERWENT; IBM_TDB 11:06			
6	BRS	270	epitax\$3 and (silicon or Si) and heav\$3 and (dop\$3 with (indium or In))	USPAT; US-PGPUB; 2002/06/24 DERWENT; IBM_TDB 14:28			
7	BRS	85	(epitax\$3 and (silicon or Si) and heav\$3 and (dop\$3 with (indium or In))) and "110"	USPAT; US-PGPUB; 2002/06/20 DERWENT; IBM_TDB 13:49			
8	BRS	19	(epitax\$3 and (silicon or Si) and heav\$3 and (dop\$3 with (indium or In))) and "110" and zone	USPAT; US-PGPUB; 2002/06/20 DERWENT; IBM_TDB 13:53			
9	BRS	85	(epitax\$3 and (silicon or Si) and heav\$3 and (dop\$3 with (indium or In))) and "<110>"	USPAT; US-PGPUB; 2002/06/20 DERWENT; IBM_TDB 13:52			
10	BRS	4	(epitax\$3 and (silicon or Si) and heav\$3 and (dop\$3 with (indium or In))) and "110" and zone and axis	USPAT; US-PGPUB; 2002/06/20 DERWENT; IBM_TDB 13:55			
11	BRS	8	(epitax\$3 and (silicon or Si) and heav\$3 and (dop\$3 with (indium or In))) and zone and (axis or orientation) and "110"	USPAT; US-PGPUB; 2002/06/20 DERWENT; IBM_TDB 13:57			

	Type	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition
12	BRS	11753	dop\$3 and (axis or orientation) and "110"	USPAT; US-PGPUB; DERWENT; IBM_TDB	2002/06/20 13:58		
13	BRS	662	semiconductor and doping and "110" and zone and (axis or orientation)	USPAT; US-PGPUB; DERWENT; IBM_TDB	2002/06/20 14:48		
14	BRS	301	(semiconductor and doping and "110" and zone and (axis or orientation)) and epitaxial	USPAT; US-PGPUB; DERWENT; IBM_TDB	2002/06/20 14:04		
15	BRS	301	((semiconductor and doping and "110" and zone and (axis or orientation)) and epitaxial) and "<110>"	USPAT; US-PGPUB; DERWENT; IBM_TDB	2002/06/20 14:05		
16	BRS	32	(semiconductor and doping and "110" and zone and (axis or orientation)) and ("110" adj (orientation or axis))	USPAT; US-PGPUB; DERWENT; IBM_TDB	2002/06/20 14:06		
17	BRS	436	substrate and (silicon or Si) and ("110" adj (axis or orientation))	USPAT; US-PGPUB; DERWENT; IBM_TDB	2002/06/20 14:52		
18	BRS	132	(substrate and (silicon or Si) and ("110" adj (axis or orientation))) and doping	USPAT; US-PGPUB; DERWENT; IBM_TDB	2002/06/20 15:26		
19	BRS	425	257/627, 628.ccls.	USPAT; US-PGPUB	2002/06/20 15:27		
20	BRS	236	257/627, 628.ccls. and substrate and dop\$3	USPAT; US-PGPUB	2002/06/20 15:28		
21	BRS	39	(257/627, 628.ccls. and substrate and dop\$3) and ("110" near (orientation or axis))	USPAT; US-PGPUB	2002/06/20 15:28		
22	BRS	270	epitax\$3 and (silicon or Si) and heav\$3 and (dop\$3 with (indium or In))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/24 14:28		
23	BRS	8	257/344, 345, 346, 408, 412.ccls. and epitaxial and (indium or In) and (antimony or Sb)	USPAT; US-PGPUB; JPO	2002/06/24 14:31		

	Type	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition
24	BRS	3	(epitax\$3 and (silicon or Si) and heav\$3 and (dop\$3 with (indium or In))) and ("110" near (zone or orientation or axis))	USPAT; US-PGPUB; JPO	2002/06/24 14:32		